Philips Semiconductors

Product specification

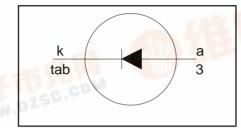
Rectifier diodes Schottky barrier

PBYL2025B series

FEATURES

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

SYMBOL



QUICK REFERENCE DATA

$$V_R = 20 \text{ V}/25 \text{ V}$$
 $I_{F(AV)} = 20 \text{ A}$
 $V_F \le 0.43 \text{ V}$

GENERAL DESCRIPTION

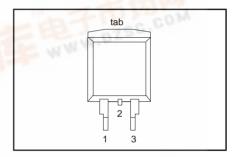
Schottky rectifier diodes intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

The PBYL2025B series is supplied in the SOT404 surface mounting package.

PINNING

PIN	DESCRIPTION	
1	no connection	
2	cathode 1	
3	anode	
tab	cathode	
	l .	

SOT404



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
		PBYL20		20B	25B	
V_{RRM}	Peak repetitive reverse voltage		-	20	25	V
V_{RWM}	Working peak reverse voltage	13 m	-	20	25	V
V_R	Continuous reverse voltage	T _{mb} ≤ 120 °C	-	20	25	V
$I_{F(AV)}$	Average rectified forward current	square wave; $\delta = 0.5$; $T_{mb} \le 131$ °C	-	2	20	Α
I _{FRM}	Repetitive peak forward current	square wave; $\delta = 0.5$; $T_{mb} \le 131$ °C	-	4	10	А
I _{FSM}	Non-repetitive peak forward current	t = 10 ms t = 8.3 ms sinusoidal; T _j = 125 °C prior to surge: with reapplied V _{SSWeen}	E		80 00	A A
I _{RRM}	Peak repetitive reverse surge current	surge; with reapplied V _{RRM(max)} pulse width and repetition rate limited by T _{i max}	-		2	А
T_{j}	Operating junction temperature		-	1	50	°C
T_{stg}	Storage temperature	SC-CO	- 65	1	75	°C

1. It is not possible to make connection to pin 2 of the SOT404 package.



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THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb}	Thermal resistance junction to mounting base		1	-	1.5	K/W
$R_{th j-a}$		pcb mounted, minimum footprint, FR4 board	-	50	-	K/W

ELECTRICAL CHARACTERISTICS

T_i = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{F}	Forward voltage	$I_{\rm F} = 20 \text{ A}; T_{\rm i} = 150^{\circ}\text{C}$	-	0.36	0.43	V
'		$I_{\rm F} = 20 \text{ A}; T_{\rm i} = 125 ^{\circ}\text{C}$	-	0.39	0.45	V
		$I_{\rm F} = 40 \text{ A}$; $T_{\rm i} = 125 ^{\circ}\text{C}$	-	0.55	0.62	V
		$I_{\rm F} = 40 \text{A}$	-	0.59	0.65	V
I _R	Reverse current	$\dot{V}_{R} = V_{RWM}$	-	0.4	10	mΑ
'`		$V_{R} = V_{RWM}^{CWM}$; $T_{i} = 100^{\circ}C$	-	30	60	mΑ
C _d	Junction capacitance	$V_R = V_{RWM}$; $T_j = 100^{\circ}C$ $V_R = 5 \text{ V}$; $f = 1 \text{ MHz}$, $T_j = 25^{\circ}C \text{ to } 125^{\circ}C$	-	1230	-	pF

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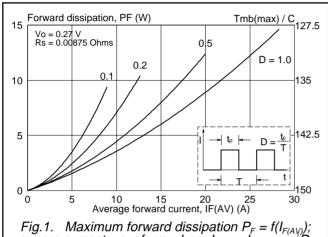


Fig.1. Maximum forward dissipation $P_F = f(I_{F(AV)});$ square current waveform where $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}.$

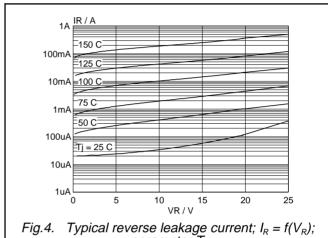


Fig.4. Typical reverse leakage current; $I_R = f(V_R)$; parameter T_i

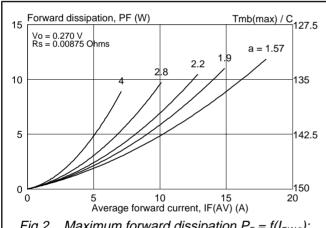
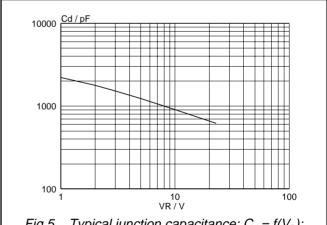


Fig.2. Maximum forward dissipation $P_F = f(I_{F(AV)});$ square current waveform where $I_{F(AV)} = I_{F(RMS)} \times \sqrt{D}.$



Typical junction capacitance; $C_d = f(V_R)$; f = 1 MHz; $T_j = 25^{\circ}\text{C}$ to 125°C .

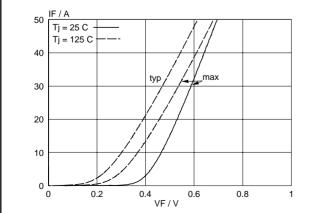


Fig.3. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_i

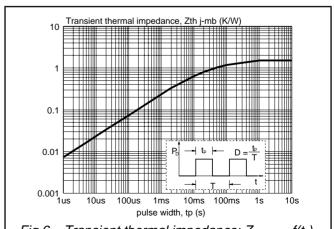
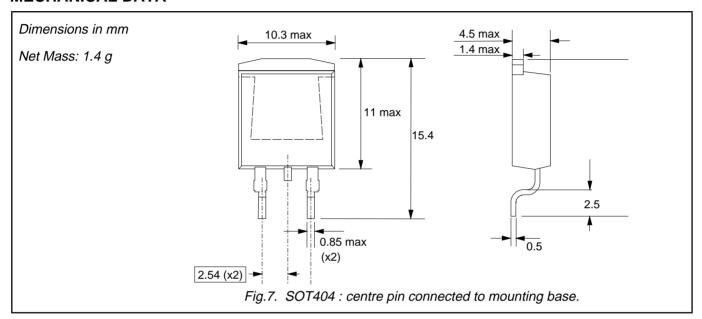


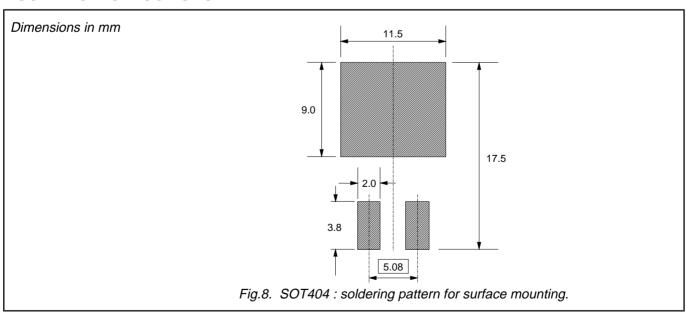
Fig.6. Transient thermal impedance; $Z_{th i-mb} = f(t_p)$.

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MECHANICAL DATA



MOUNTING INSTRUCTIONS



Notes
1. Epoxy meets UL94 V0 at 1/8".

Rectifier	diodes
Schottky	barrier

PBYL2025B series

DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification This data sheet contains preliminary data; supplementary data may be published late				
Product specification This data sheet contains final product specifications.				
Limiting values				

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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